

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX373F, TC74LCX373FK

Low-Voltage Octal D-Type Latch with 5-V Tolerant Inputs and Outputs

The TC74LCX373 is a high-performance CMOS octal D-type latch. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

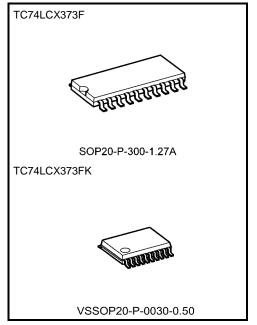
The device is designed for low-voltage (3.3 V) $V_{\rm CC}$ applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 8 bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high-impedance state.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: VCC = 1.65 V to 3.6 V
- High-speed operation: $t_{pd} = 8.0 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Available in JEITA SOP, VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 373 type



Weight

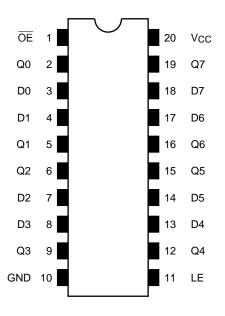
SOP20-P-300-1.27A : 0.22 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Note: The Electrical Characteristics of $V_{\rm CC}$ = 1.8 \pm 0.15 V is only applicable for products which manufactured from January 2009 onward.

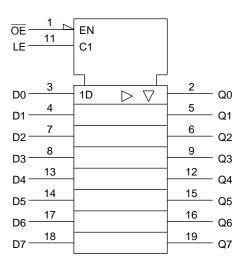
Start of commercial production 1994-10



Pin Assignment (top view)



IEC Logic Symbol



Truth Table

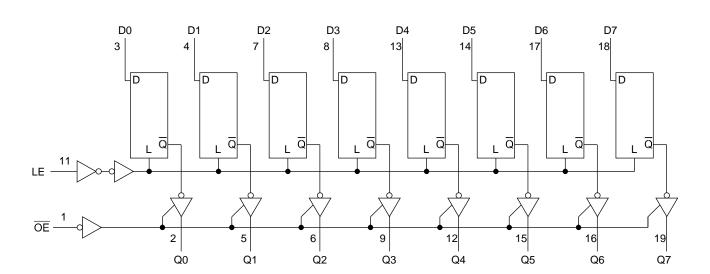
	Outpute		
ŌĒ	LE	D	Outputs
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	lıĸ	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC Vcc/ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Dower cumply voltage	Voc	1.65 to 3.6	V
Power supply voltage	Vcc	1.5 to 3.6 (Note 2)	V
Input voltage	VIN	0 to 5.5	V
Output valtage	\/ -	0 to 5.5 (Note 3)	V
Output voltage	Vout	0 to V _{CC} (Note 4)	
Output ourrent	1/1	±24 (Note 5)	A
Output current	IOH/IOL	±12 (Note 6)	mA
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: VCC = 3.0 to 3.6 V

Note 6: VCC = 2.7 to 3.0 V

Note 7: VIN = 0.8 to 2.0 V, VCC = 3.0 V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		C: made al	Took Co.	- disi		N.A.:	Max	l lmit
Characteris	SUCS	Symbol	Test Co	Test Condition		Min		Unit
			_		1.65 to2.3	Vcc × 0.9	_	
	H-level	VIH			2.3 to2.7	1.7	_	
Input voltage					2.7 to 3.6	2.0	_	V
					1.65 to2.3	_	Vcc × 0.1	V
	L-level	VIL	_	-	2.3 to2.7	_	0.7	
					2.7 to 3.6	_	0.8	
				$I_{OH} = -100 \mu A$	1.65 to 3.6	V _{CC} - 0.2		
				IOH = -4 mA	1.65	1.05	_	
	H-level	Voн	V _{IN} = V _{IH} or V _{IL}	IOH = -8 mA	2.3	1.7	_	V
	n-ievei	VOH		$I_{OH} = -12 \text{ mA}$	2.7	2.2		
				IOH = -18 mA	3.0	2.4		
Output voltage				IOH = -24 mA	3.0	2.2	_	
Output voltage	L-level V		V _{IN} = V _{IH} or V _{IL}	IOL = 100 μA	1.65 to 3.6	_	0.2	
				$I_{OL} = 4 \text{ mA}$	1.65	_	0.45	
		V _{OL}		IOL = 8 mA	2.3	_	0.7	
	LICVCI			I _{OL} = 12 mA	2.7	_	0.4	
				IOL = 16 mA	3.0		0.4	
				$I_{OL} = 24 \text{ mA}$	3.0		0.55	
Input leakage current		liN	V _{IN} = 0 to 5.5 V		1.65 to 3.6		±5.0	μΑ
3-state output OFF state current		loz	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.65 to 3.6	_	±5.0	μА
Power-off leakage current IOFF		loff	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μΑ
Outroport supply supply		Icc	V _{IN} = V _{CC} or GND		1.65 to 3.6	_	10.0	
Quiescent supply curre	an.	icc	V _{IN} /V _{OUT} = 3.6 to 5.5 V		1.65 to 3.6	_	±10.0	μΑ
Increase in ICC per inp	ut	Δlcc	VIH = VCC - 0.6 V	(per 1 input)	2.7 to 3.6	_	500	



AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition		Min	Min Max	
Gharacteristics	Cymbol	rest condition	V _{CC} (V)	IVIIII	Max	Unit
Propagation delay time (D-Q)			1.8 ± 0.15	_	30.0	ns
	tpLH	Figure 1, Figure 2	2.5 ± 0.2		10.0	
(D-Q)	tpHL	rigure 1,1 igure 2	2.7		9.0	113
			3.3 ± 0.3	1.5	8.0	
			1.8 ± 0.15		30.0	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	_	10.5	ns
(LE-Q)	t _{pHL}	rigule 1, rigule 2	2.7	_	9.5	115
			3.3 ± 0.3	1.5	8.5	
			1.8 ± 0.15	_	34.0	
Output anable time	t _{pZL}	Figure 1 Figure 2	2.5 ± 0.2	_	17.0	200
Output enable time	t _{pZH}	Figure 1, Figure 3	2.7	_	9.5	ns
			3.3 ± 0.3	1.5	8.5	
		Figure 1, Figure 3	1.8 ± 0.15	_	32.0	ns
Output disable time	tpLZ		2.5 ± 0.2	_	16.0	
	tpHZ		2.7		8.5	
			3.3 ± 0.3	1.5	7.5	
		Figure 1, Figure 2	1.8 ± 0.15	12.0	_	ns
Minimum pulse width	((1)		2.5 ± 0.2	6.0	_	
(LE)	t _W (H)		2.7	4.0	_	
			3.3 ± 0.3	3.3	_	
			1.8 ± 0.15	10.0	_	
NAME OF THE OWNER O			2.5 ± 0.2	5.0	_	
Minimum setup time	ts	Figure 1, Figure 2	2.7	2.5	_	ns
			3.3 ± 0.3	2.5	_	
			1.8 ± 0.15	1.5	_	
Minimum hold time	<u>.</u>	Figure 1, Figure 2	2.5 ± 0.2	1.5	_	no
	th		2.7	1.5	_	ns
			3.3 ± 0.3	1.5	_	
Output to output alicen	tosLH	/A1-1-1	2.7		_	
Output to output skew	tosHL	(Note)	3.3 ± 0.3		1.0	ns

Note: Parameter guaranteed by design.

 $(\mathsf{tosLH} = |\mathsf{tpLHm} - \mathsf{tpLHn}|,\, \mathsf{tosHL} = |\mathsf{tpHLm} - \mathsf{tpHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.5 ns, CL = 50 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	VOLP	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	8.0	٧
Quiet output minimum dynamic VOL	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V

Capacitive Characteristics (Ta = 25°C)

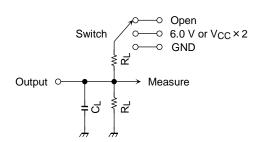
Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Input capacitance	CIN	_	3.3	7	pF
Output capacitance	Cout	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (No	te) 3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

ICC (opr) = CPD · VCC · fIN + ICC/8 (per bit)

AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
	6.0 V	@ V _{CC} =3.3±0.3V @ V _{CC} =2.7V	
t _{pLZ} , t _{pZL}	V _{CC} ×2 @ V _{CC} =2.5±0.2V @ V _{CC} =1.8±0.15V		
tpHZ, tpZH	GND		

Figure 1



AC Waveform

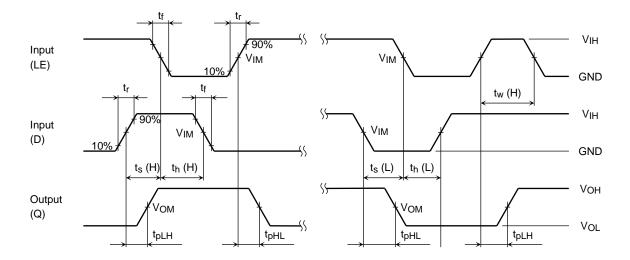


Figure 2 t_{pLH}, t_{pHL}, t_w, t_s, t_h

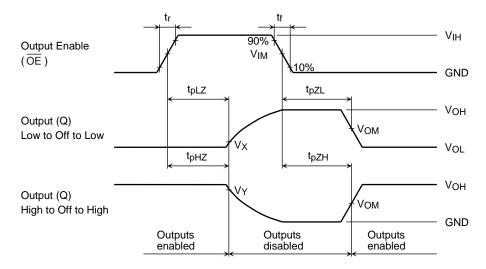


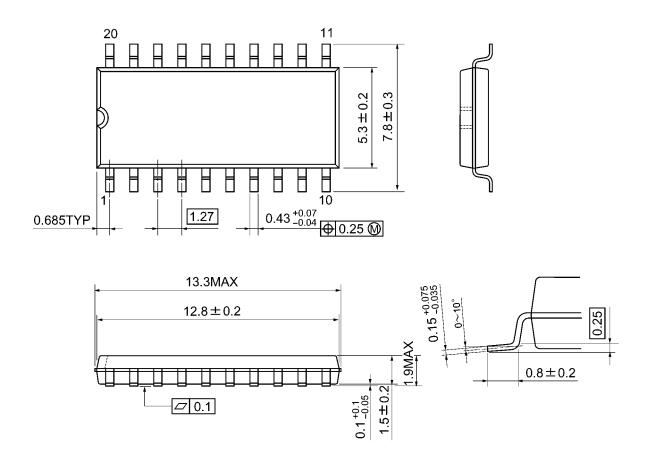
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

			Vcc					
	Symbol	$3.3 \pm 0.3 \text{ V}$ 2.7 V	2.5 ± 0.2 V	1.8 ± 0.15 V				
Input	VIH	2.7 V	Vcc	Vcc				
	VIM	1.5 V	V _{CC} /2	V _{CC} /2				
	t _r , t _f	2.5 ns	2.0 ns	2.0 ns				
Output	Vом	1.5 V	Vo _H /2	V _{OH} /2				
	Vx	V _{OL} +0.3 V	V _{OL} +0.15 V	V _{OL} +0.15 V				
	VY	Voh -0.3 V	Voн -0.15 V	Voн -0.15 V				
Load	CL	50 pF	30 pF	30 pF				
	RL	500 Ω	500 Ω	1 kΩ				



Package Dimensions

SOP20-P-300-1.27A Unit: mm

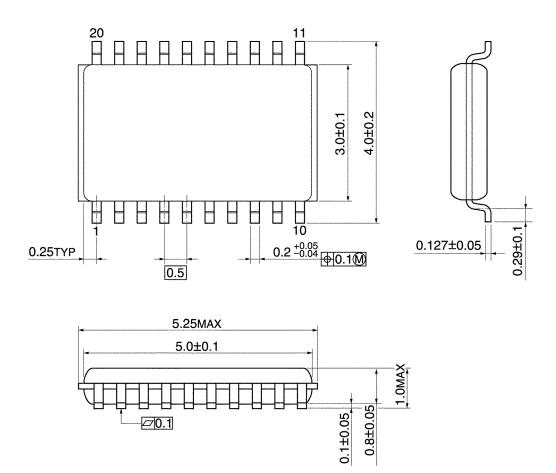


Weight: 0.22 g (typ.)



Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



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